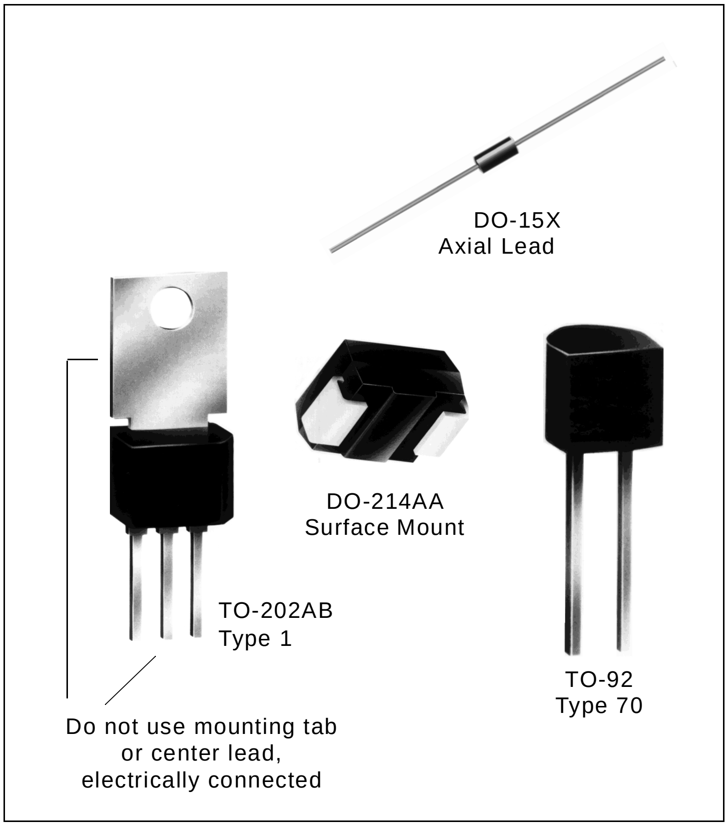
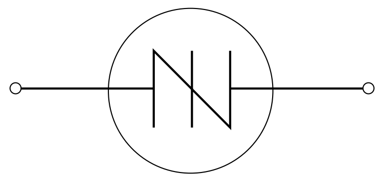




SIDAC

(95 - 330 Volts)

General Description

The Sidac is a silicon bilateral voltage triggered switch with greater power-handling capabilities than standard diacs. Upon application of a voltage exceeding the Sidac breakover voltage point, the Sidac switches on through a negative resistance region to a low on-state voltage. Conduction will continue until the current is interrupted or drops below the minimum holding current of the device.

Teccor offers the complete voltage range (95-330) over three different packages:

- TO-92 (95-280 volts)
- Axial lead DO-15X (95-280 volts)
- Surface Mount DO-214AA (95-280 volts)
- TO-202AB (190-330 volts)

Teccor's Sidacs feature glass passivated junctions to ensure a rugged and dependable device capable of withstanding harsh environments.

Variations of devices covered in this data sheet are available for custom design applications. Please consult the factory for more information.

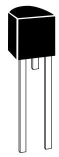
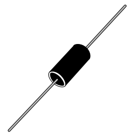
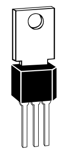
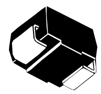
Applications

- **High voltage lamp ignitors**
- **Natural gas ignitors**
- **Gas oil ignitors**
- **High voltage power supplies**
- **Xenon ignitors**
- **Over voltage protector**
- **Pulse generators**
- **Fluorescent lighting ignitors**
- **HID lighting ignitors**

Features

- **AC circuit oriented**
- **Glass-passivated junctions**
- **High surge current capability**

Electrical Specifications

Type	Part No.				$I_{T(RMS)}$	V_{DRM}	V_{BO}		I_{DRM}	I_{BO}
	 TO-92 E Package	 DO-15X G Package	 TO-202AB F Package	 DO-214AA S Package	On-State RMS Current $T_J \leq 125°C$ 50/60Hz Sine Wave (7) (8) Amps	Repetitive Peak Off-State Voltage Volts	Breakover Voltage 50/60Hz Sine Wave (1) Volts		Repetitive Peak Off-State Current 50/60Hz Sine Wave $V=V_{DRM}$ µAmps	Breakover Current 50/60Hz Sine Wave µAmps
	See "Package Dimensions" section for variations.				MAX	MIN	MIN	MAX	MAX	MAX
	K1050E70	**K1050G**		**K1050S**	**1.0**	**±90**	**95**	**113**	**5**	**10**
	K1100E70	**K1100G**		**K1100S**	**1.0**	**±90**	**104**	**118**	**5**	**10**
	K1200E70	**K1200G**		**K1200S**	**1.0**	**±90**	**110**	**125**	**5**	**10**
	K1300E70	**K1300G**		**K1300S**	**1.0**	**±90**	**120**	**138**	**5**	**10**
	K1400E70	**K1400G**		**K1400S**	**1.0**	**±90**	**130**	**146**	**5**	**10**
	K1500E70	**K1500G**		**K1500S**	**1.0**	**±90**	**140**	**170**	**5**	**10**
	K2000E70	**K2000G**	**K2000F1**	**K2000S**	**1.0**	**±180**	**190**	**215**	**5**	**10**
	K2200E70	**K2200G**	**K2200F1**	**K2200S**	**1.0**	**±180**	**205**	**230**	**5**	**10**
	K2400E70	**K2400G**	**K2400F1**	**K2400S**	**1.0**	**±190**	**220**	**250**	**5**	**10**
			K2401F1		**1.0 (10)**	**±190**	**220**	**250**	**5**	**10**
	K2500E70	**K2500G**	**K2500F1**	**K2500S**	**1.0**	**±190**	**240**	**280**	**5**	**10**
			K3000F1		**1.0**	**±190**	**270**	**330**	**5**	**10**

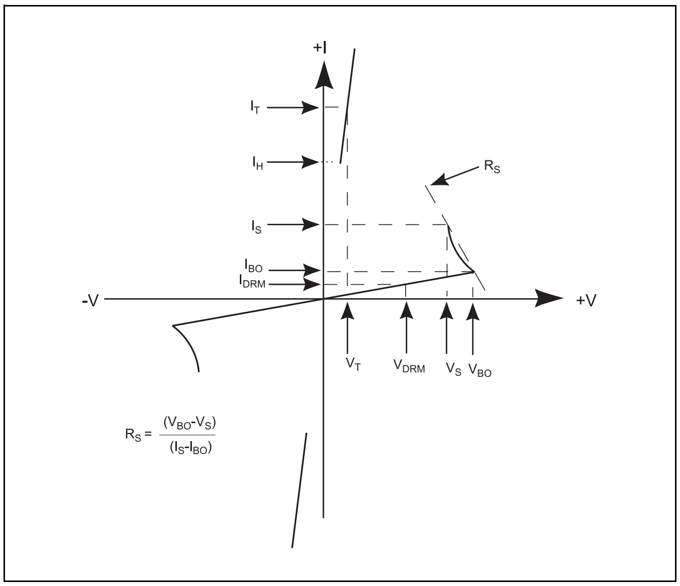
General Notes

- All measurements are made at 60Hz with a resistive load at an ambient temperature of +25°C unless otherwise specified.
- Storage temperature range (T_S) is -65°C to +150°C.
- The case (T_C) or lead (T_L) temperature is measured as shown on the dimensional outline drawings. See "Package Dimensions" section of this catalog.
- Junction temperature range (T_J) is -40°C to +125°C.
- Lead solder temperature is a maximum of +230°C for 10 seconds maximum; ≥ 1/16" (1.59mm) from case.

Electrical Specification Notes

(1) See Figure 9.6 for V_{BO} change vs junction temperature.
(2) See Figure 9.7 for I_{BO} vs junction temperature.
(3) See Figure 9.2 for I_H vs case temperature.
(4) See Figure 9.14 for test circuit.
(5) See Figure 9.1 for more than one full cycle rating.
(6) $R_{\theta JA}$ for TO-202 Type 23 and Type 41 is 70°C/watt.
(7) $T_C \leq 90°C$ for TO-92 Sidac and $T_C \leq 105°C$ for TO-202 Sidacs. $T_L \leq 100°C$ for DO-15X and $T_L \leq 90°C$ for DO-214AA.
(8) See Figure 9.15 for clarification of Sidac operation.
(9) For best Sidac operation, the load impedance should be near or less than switching resistance.
(10) Teccor's new, improved series of sidacs is designed to ensure goodcommutationathigherswitchingfrequenciesasrequiredinignitor circuits for high intensity discharge (HID) lighting. A typical circuit for a metal halide lamp ignitor is shown in the schematic, Figure 9.3. With proper component selection this circuit will produce three pulses for ignition of Osram lamp types such as HQI-T70W, HQI-T150W, and HQI-T250W which require a minimum of three pulses at 4kV magnitude and >1µs duration each at a minimum repetition rate of 3.3kHz.

I_H		V_{TM}				I_{TSM}		R_S	dV_q/dt	dv/dt	di/dt
Dynamic Holding Current 50/60Hz Sine Wave R = 100Ω (3) (4) mAmps		Peak On-State Voltage I_T = 1 Amp Volts Max				Peak One Cycle Surge Current 50/60Hz Sine Wave (Non-Repetitive) (5) Amps		Switching Resistance $R_S = \frac{(V_{BO} - V_S)}{(I_S - I_{BO})}$ 50/60Hz Sine Wave (9)	Critical Rate-of-Rise of Turn-off Voltage at 8kHz	Critical Rate-of-Rise of Off-State Voltage at Rated V_{DRM} $T_J \leq 100°C$	Critical Rate-of-Rise of On-State Current
		Package				60Hz	50Hz	kΩ	Volts/µSec	Volts/µSec	Amps/µSec
TYP	MAX	E	G	F	S			MIN	MIN	MIN	TYP
60	**150**	**1.5**	**1.5**		**1.5**	**20**	**16.7**	**0.1**	**20**	**1500**	**150**
60	**150**	**1.5**	**1.5**		**1.5**	**20**	**16.7**	**0.1**	**20**	**1500**	**150**
60	**150**	**1.5**	**1.5**		**1.5**	**20**	**16.7**	**0.1**	**20**	**1500**	**150**
60	**150**	**1.5**	**1.5**		**1.5**	**20**	**16.7**	**0.1**	**20**	**1500**	**150**
60	**150**	**1.5**	**1.5**		**1.5**	**20**	**16.7**	**0.1**	**20**	**1500**	**150**
60	**150**	**1.5**	**1.5**		**1.5**	**20**	**16.7**	**0.1**	**20**	**1500**	**150**
60	**150**	**1.5**	**1.5**	**3.0**	**1.5**	**20**	**16.7**	**0.1**	**20**	**1500**	**150**
60	**150**	**1.5**	**1.5**	**3.0**	**1.5**	**20**	**16.7**	**0.1**	**20**	**1500**	**150**
60	**150**	**1.5**	**1.5**	**3.0**	**1.5**	**20**	**16.7**	**0.1**	**20**	**1500**	**150**
60	**150**			**3.0**		**20**	**16.7**	**2.0**	**42**	**1500**	**150**
60	**150**	**1.5**	**1.5**	**3.0**	**1.5**	**20**	**16.7**	**0.1**	**20**	**1500**	**150**
60	**150**			**3.0**		**20**	**16.7**	**0.1**	**20**	**1500**	**150**



V-I Characteristics

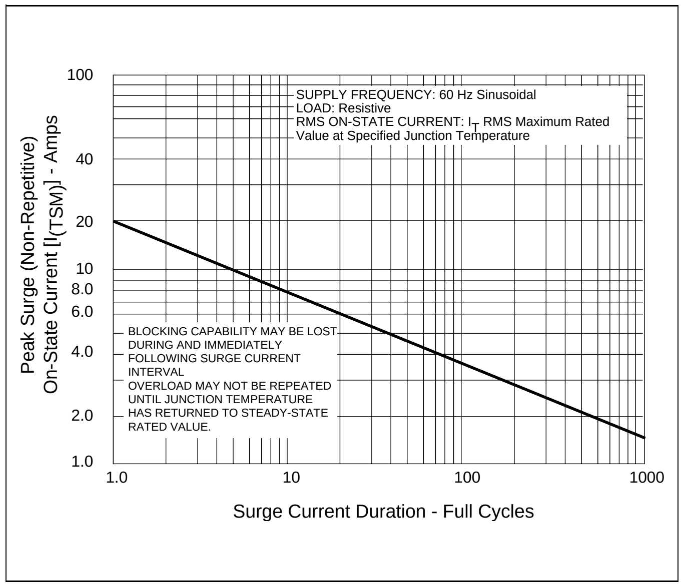
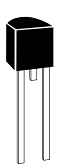
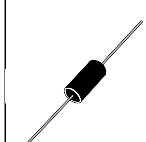
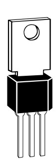
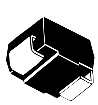


Figure 9.1 Peak Surge Current vs Surge Current Duration

THERMAL RESISTANCE (STEADY STATE) $R_{\theta JC}$ [$R_{\theta JA}$] °C/W (TYPICAL)			
 E	 G	 F (6)	 S
35 [95]	**18 [75]**	**7 [45]**	**30 [85]**

Electrical Specifications

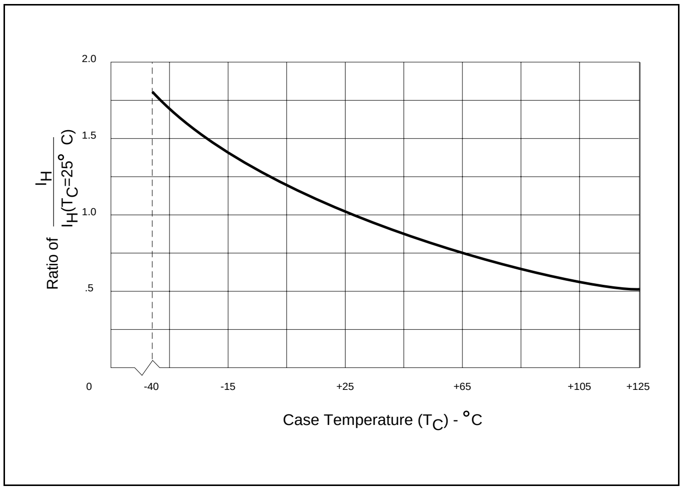


Figure 9.2 Normalized DC Holding Current vs Case/Lead Temperature

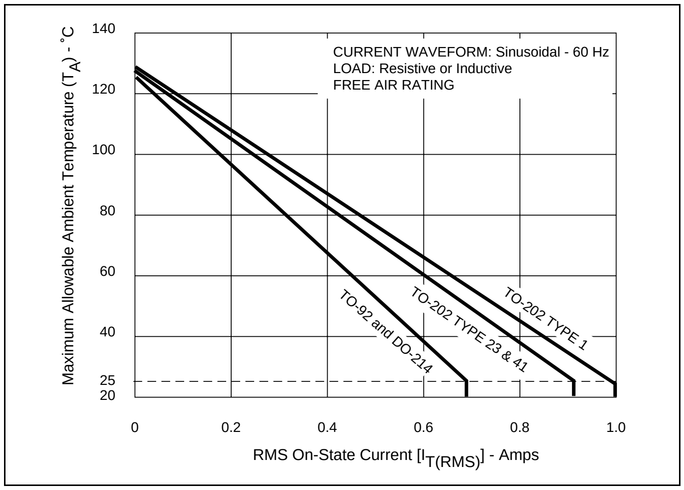


Figure 9.5 Maximum Allowable Ambient Temperature vs On-State Current

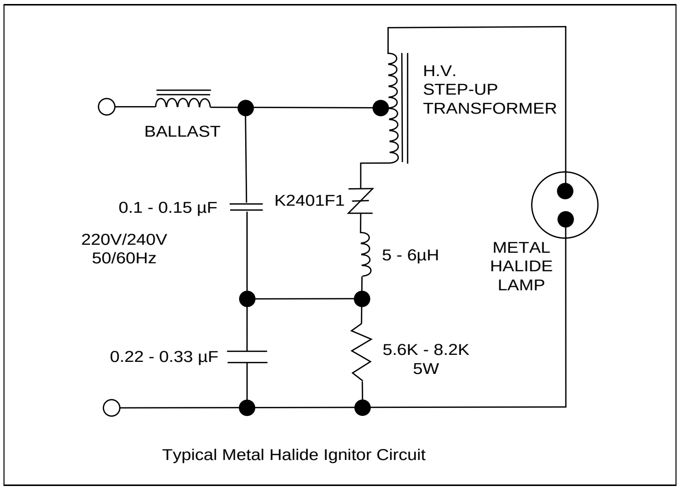


Figure 9.3 Typical Metal Halide Ignitor Circuit

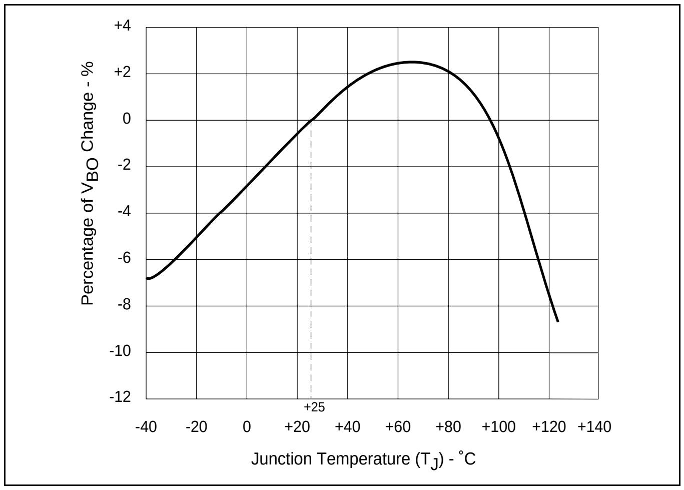


Figure 9.6 Normalized V_{BO} Change vs Junction Temperature

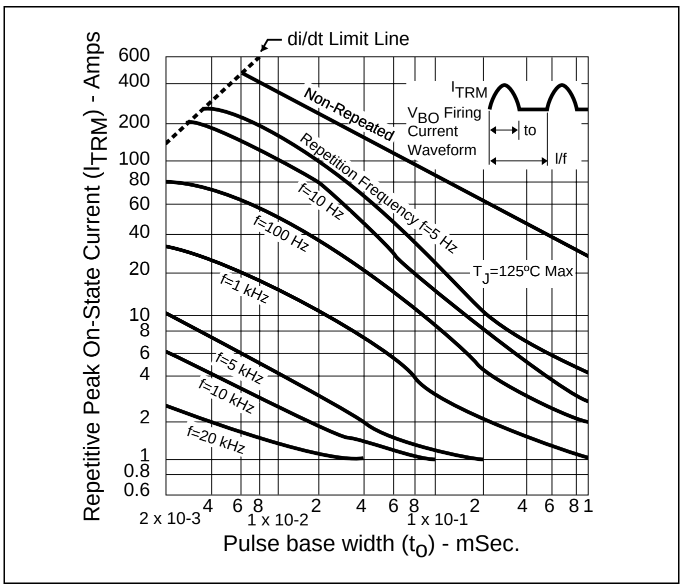


Figure 9.4 Repetitive Peak On-State Current (I_{TRM}) vs Pulse Width at Various Frequencies

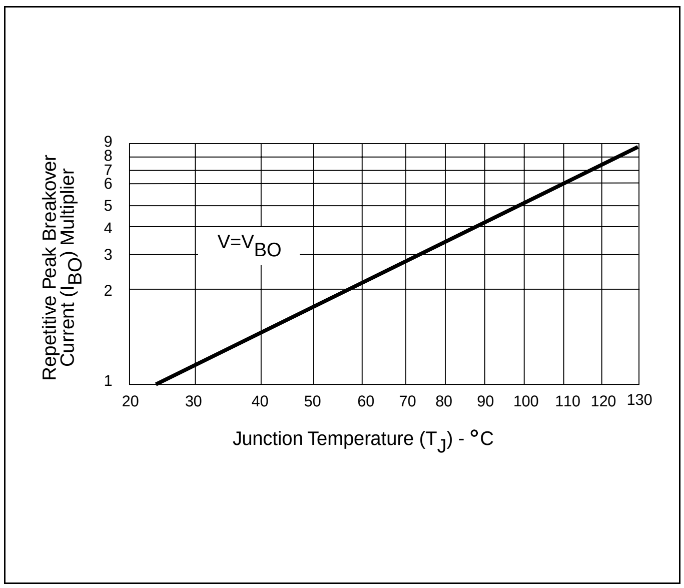


Figure 9.7 Normalized Repetitive Peak Breakover Current vs Junction Temperature

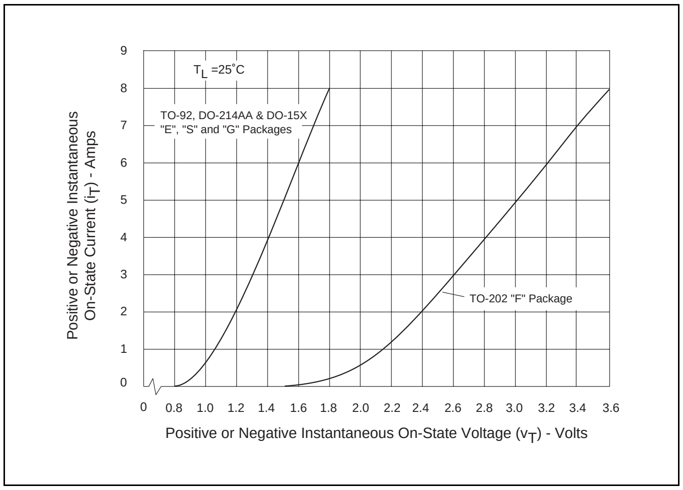


Figure 9.8 On-State Current vs On-State Voltage (Typical)

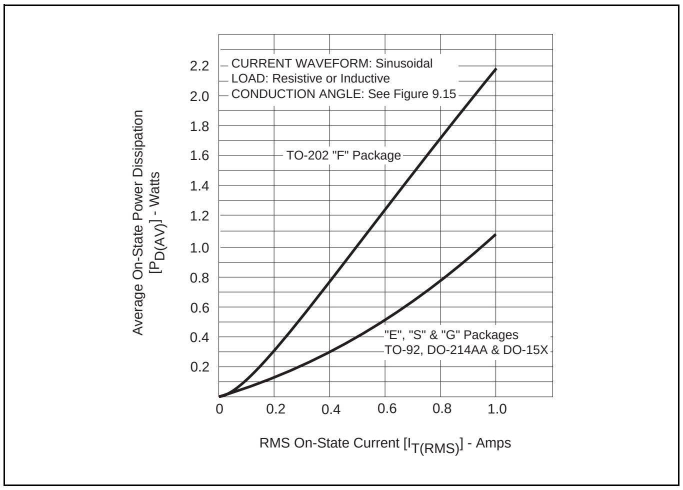


Figure 9.9 Power Dissipation (Typical) vs On-State Current

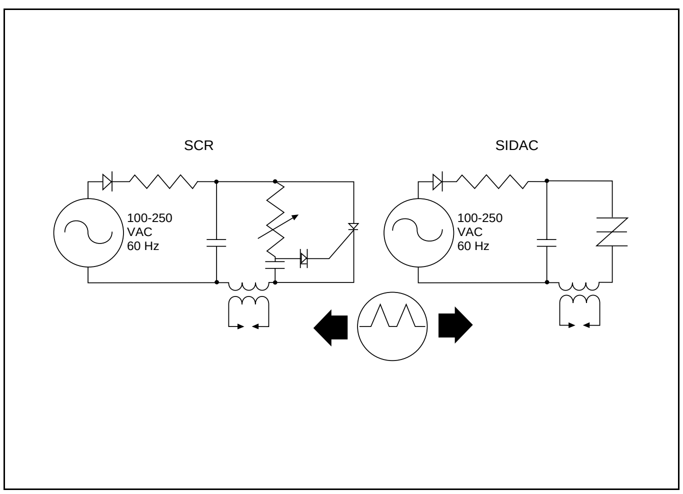


Figure 9.10 Comparison of Sidac vs SCR

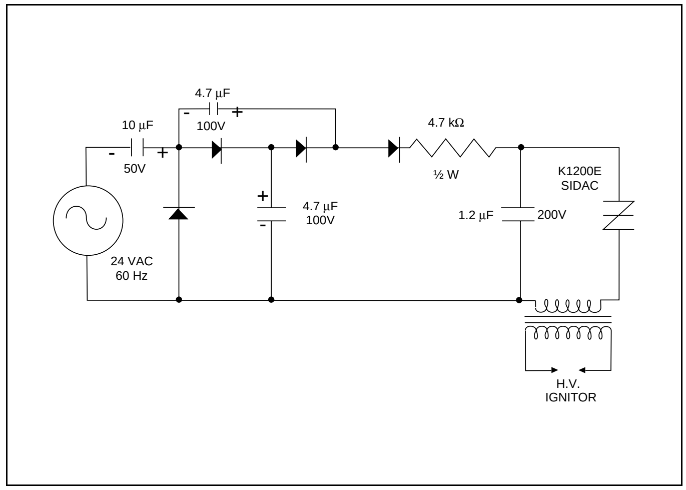


Figure 9.11 Ignitor Circuit (Low Voltage Input)

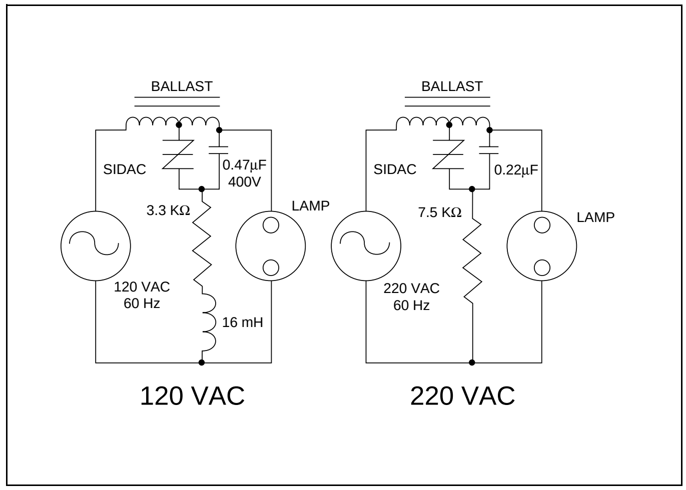


Figure 9.12 Typical High Pressure Sodium Lamp Firing Circuit

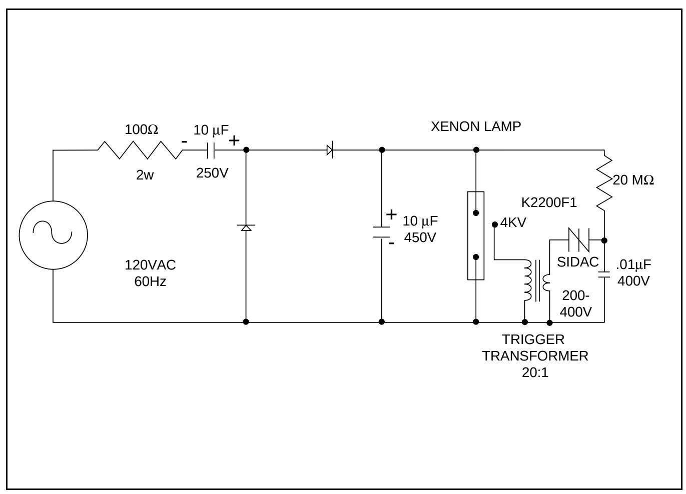


Figure 9.13 Xenon Lamp Flashing Circuit

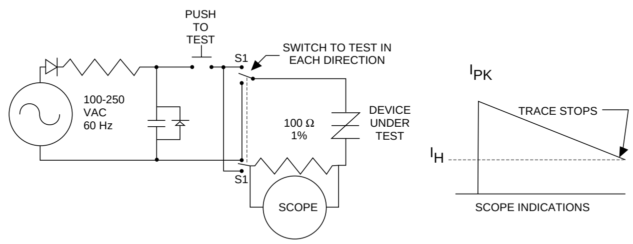


Figure 9.14 Dynamic Holding Current Test Circuit for Sidacs

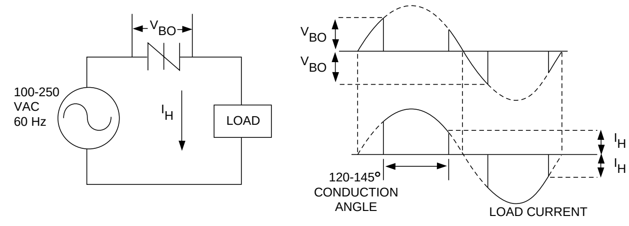


Figure 9.15 Basic Sidac Circuit

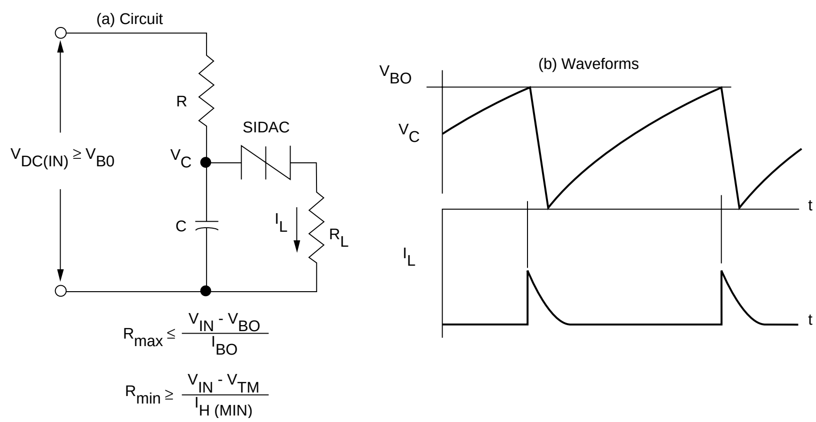
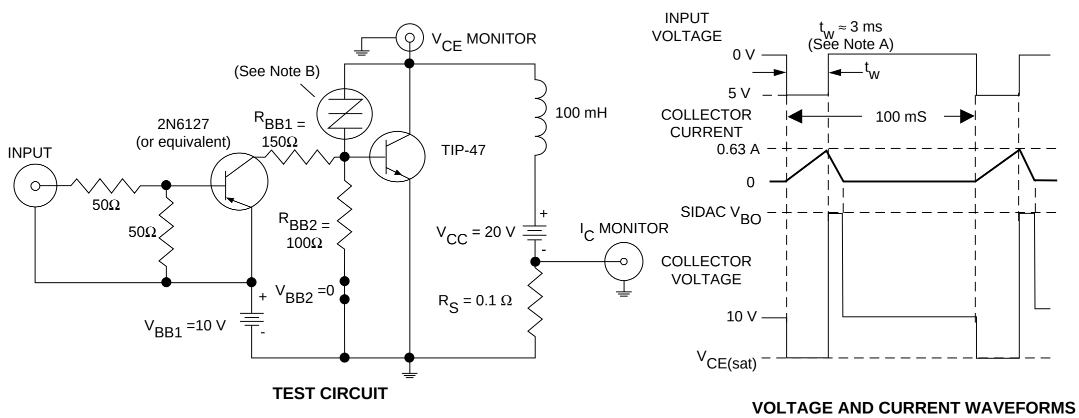


Figure 9.16 Relaxation oscillator Using a Sidac



NOTE A: Input pulse width is increased until I_{CM} = 0.63A.

NOTE B: Sidac (or Diac or series of Diacs) chosen so that V_{BO} is just below V_{CEO} rating of transistor to be protected. The Sidac (or Diac) eliminates a reverse breakdown of the transistor in inductive switching circuits where otherwise the transistor could be destroyed.

Figure 9.17 Sidac Added to Protect Transistor for Typical Transistor Inductive Load Switching Requirements